TOSHIBA Photocoupler GaAs IRED & Photo-Transistor

# **TLP781, TLP781F**

Office Equipment
Household Appliances
Solid State Relays
Switching Power Supplies
Various Controllers
Signal Transmission between Different Voltage
Circuits

The TOSHIBA TLP781 consists of a silicone photo–transistor optically coupled to a gallium arsenide infrared emitting diode in a four lead plastic DIP (DIP4) with having high isolation voltage (AC: 5kV<sub>RMS</sub> (min)).

- TLP781 : 7.62mm pitch type DIP4
- TLP781F: 10.16mm pitch type DIP4
- Collector-emitter voltage: 80V (min)
- Current transfer ratio: 50% (min)
  Rank GB: 100% (min)
- Isolation voltage: 5000V<sub>rms</sub> (min)
- UL recognized: UL1577, file No. E67349
- BSI approved: BS EN60065:2002

Approved no.8961

BS EN60950-1:2006

Approved no.8962

• SEMKO approved:EN60065:2002

Approved no.800514

EN60950-1:2001, EN60335-1:2002

Approved no.800517

Option(D4)type

VDE approved DIN EN60747-5-5

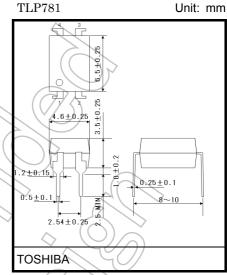
Certificate No. 40021173

(Note): When an EN60747-5-5 approved type is needed,

Please designate "Option (D4)"

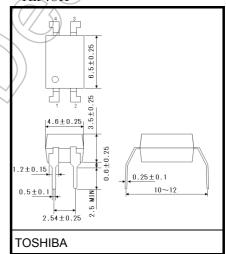
Construction mechanical rating

|                      | 7.62mm Pitch<br>Standard Type | 10.16mm Pitch<br>TLPxxxF Type |
|----------------------|-------------------------------|-------------------------------|
| Creepage distance    | 6.5mm (min)                   | 8.0mm (min)                   |
| Clearance            | 6.5mm (min)                   | 8.0mm (min)                   |
| Insulation thickness | 0.4mm (min)                   | 0.4mm (min)                   |



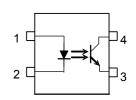
Weight: 0.25g (typ.)

TLP781F Unit: mm



Weight: 0.25g (typ.)

Pin Configurations (top view)



1 : Anode

2: Cathode

3: Emitter

4 : Collector



#### **Current Transfer Ratio**

| Туре   | Classification<br>(Note 1) | Current Transfer Ratio (%)  (I <sub>C</sub> / I <sub>F</sub> )  I <sub>F</sub> = 5mA, V <sub>CE</sub> = 5V, Ta = 25°C  Min Max |     | Marking Of Classification          |
|--------|----------------------------|--|-----|------------------------------------|
|        | (None)                     | 50   | 600 | Blank, Y+, YE, G, G+, GR, B, BL,GB |
|        | Rank Y                     | 50   | 150 | YE                                 |
|        | Rank GR                    | 100  | 300 | GR                                 |
|        | Rank BL                    | 200  | 600 | BL                                 |
| TLP781 | Rank GB                    | 100  | 600 | GB                                 |
|        | Rank YH                    | 75   | 150 | Y+ ((// ))                         |
|        | Rank GRL                   | 100  | 200 | G                                  |
|        | Rank GRH                   | 150  | 300 | G+                                 |
|        | Rank BLL                   | 200  | 400 | В                                  |

(Note 1): Ex. rank GB: TLP781 (GB)

(Note 2): Application type name for certification test, please use standard product type name, i. e. TLP781 (GB): TLP781

### Absolute Maximum Ratings (Ta = 25°C)

|          | Characteristic                                  | Symbol                | Rating     | Unit             |
|----------|---|-----------------------|------------|------------------|
|          | Forward current                                 | (F                    | 60         | ∕/mA             |
|          | Forward current derating (Ta ≥ 39°C)            | Δl <sub>F</sub> / °C  | =0.7       | mA / °C          |
|          | Pulse forward current (Note 3)                  | IFP                   | // 1       | Α                |
| LED      | Power dissipation                               | PD                    | 100        | mW               |
|          | Power dissipation derating                      | DΔP <sub>D</sub> / °C | -1.0       | mW / °C          |
|          | Reverse voltage                                 | V <sub>R</sub>        | 5          | V                |
|          | Junction temperature                            | Tj (F                 | 125        | °C               |
|          | Collector-emitter voltage                       | V <sub>CE</sub> O     | 80         | V                |
|          | Emitter-collector voltage                       | YECO                  | 7          | V                |
| Detector | Collector current                               | (k)                   | 50         | mA               |
| Dete     | Power dissipation                               | PC                    | 150        | mW               |
|          | Power dissipation derating (Ta ≥ 25°C)          | ΔP <sub>C</sub> /°C   | -1.5       | mW / °C          |
|          | Junction temperature                            | Tj                    | 125        | °C               |
| Ope      | rating temperature range                        | T <sub>opr</sub>      | -55 to 110 | °C               |
| Stora    | age temperature range                           | T <sub>stg</sub>      | -55 to 125 | °C               |
| Lead     | d soldering temperature (10s)                   | T <sub>sol</sub>      | 260        | °C               |
| Tota     | package power dissipation                       | P <sub>T</sub>        | 250        | mW               |
|          | I package power dissipation derating<br>≥ 25°C) | ΔP <sub>T</sub> / °C  | -2.5       | mW / °C          |
| Isola    | ation voltage (Note 4)                          | BV <sub>S</sub>       | 5000       | V <sub>rms</sub> |

(Note): Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

(Note 3): 100 µs pulse, 100 Hz frequency

(Note 4): AC, 1 minute, R.H. $\leq$  60%. Apply voltage to LED pin and detector pin together.

### **Recommended Operating Conditions**

| Characteristic        | Symbol           | Min | Тур. | Max | Unit |
|-----------------------|------------------|-----|------|-----|------|
| Supply voltage        | V <sub>CC</sub>  | _   | 5    | 24  | V    |
| Forward current       | lF               | _   | 16   | 25  | mA   |
| Collector current     | IC               | _   | 1    | 10  | mA   |
| Operating temperature | T <sub>opr</sub> | -25 | _    | 85  | °C   |

(Note): Recommended operating conditions are given as a design guideline to obtain expected performance of the device.

Additionally, each item is an independent guideline respectively.

In developing designs using this product, please confirm specified characteristics shown in this document.

## Individual Electrical Characteristics (Ta = 25°C)

|          | Characteristic                      | Symbol                | Test Condition                    | Min         | Тур. | Max | Unit |
|----------|-------------------------------------|-----------------------|-----------------------------------|-------------|------|-----|------|
|          | Forward voltage                     | $V_{F}$               | I <sub>F</sub> = 10 mA            | \dagger 1.0 | 1.15 | 1.3 | V    |
| ED       | Reverse current                     | I <sub>R</sub>        | V <sub>R</sub> = 5 V              | -(          | 7-1  | 10  | μΑ   |
|          | Capacitance                         | C <sub>T</sub>        | V = 0, f = 1 MHz                  | (E/         | 30   | -   | pF   |
|          | Collector–emitter breakdown voltage | V <sub>(BR)</sub> CEO | I <sub>C</sub> = 0.5 mA           | 80~         | //_  | ١   | ٧    |
| Detector | Emitter–collector breakdown voltage | V <sub>(BR)</sub> ECO | IE = 0.1 mA                       | <u></u>     | ı    | ı   | V    |
| Dete     | Collector dark current              | In/loss)              | V <sub>CE</sub> = 24 V            | _           | 0.01 | 0.1 | μA   |
|          | Collector dark current              | ID(ICEO)              | V <sub>CE</sub> = 24 V, Ta = 85°C |             | 0.6  | 50  | μΑ   |
|          | Capacitance (collector to emitter)  | CCE                   | V = 0, f = 1 MHz                  | _           | 10   | _   | pF   |

## Coupled Electrical Characteristics (Ta = 25°C)

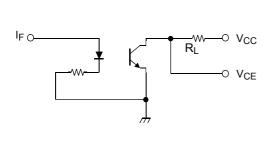
|                                      | -/                                    |  |         |     |      |     |      |
|--------------------------------------|---------------------------------------|--|---------|-----|------|-----|------|
| Characteristic                       | Symbol                                | Test Condition                                 | 1       | Min | Тур. | Max | Unit |
| Current transfer ratio               | I <sub>C</sub> /I <sub>F</sub>        | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     |         | 50  | _    | 600 | %    |
| Current transfer fatto               | 10715                                 |  | Rank GB | 100 | _    | 600 | /0   |
| Saturated CTR                        | 1-11-                                 | IF = 1 mA, V <sub>CE</sub> = 0.4 V             |         | _   | 60   | -   | %    |
| Saturated CTR                        | I <sub>C</sub> / I <sub>F (sat)</sub> |  | Rank GB | 30  | _    | _   | 70   |
|                                      |                                       | I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA |         | _   | -    | 0.4 |      |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat)                 | I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA |         | _   | 0.2  | _   | V    |
|                                      |                                       |  | Rank GB | _   | -    | 0.4 |      |

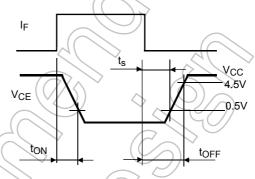
### Isolation Characteristics (Ta = 25°C)

| Characteristic                | Symbol         | Test Condition                | Min                | Тур.             | Max | Unit             |
|-------------------------------|----------------|-------------------------------|--------------------|------------------|-----|------------------|
| Capacitance (input to output) | CS             | V <sub>S</sub> = 0, f = 1 MHz | _                  | 0.8              | _   | pF               |
| Isolation resistance          | R <sub>S</sub> | V <sub>S</sub> = 500 V        | 1×10 <sup>12</sup> | 10 <sup>14</sup> | _   | Ω                |
|                               |                | AC, 1 minute                  | 5000               | -                | _   | \/               |
| Isolation voltage             | $BV_S$         | AC, 1 second, in oil          | _                  | 10000            | _   | V <sub>rms</sub> |
|                               |                | DC, 1 minute, in oil          | _                  | 10000            | _   | Vdc              |

## **Switching Characteristics (Ta = 25°C)**

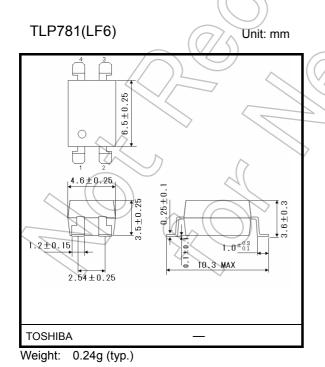
| Characteristics | Symbol           | Test Condition  | Min         | Тур.  | Max | Unit |
|-----------------|------------------|---|-------------|-------|-----|------|
| Rise time       | t <sub>r</sub>   |   | _           | 2     | _   |      |
| Fall time       | t <sub>f</sub>   | Vcc = 10 V. lc = 2 mA   | _           | 3     | _   |      |
| Turn-on time    | t <sub>on</sub>  | $V_{CC}$ = 10 V, $I_C$ = 2 mA<br>$R_L$ = 100 $\Omega$                               | 7           | 3     | _   | μs   |
| Turn-off time   | t <sub>off</sub> |   |             | 3     | _   |      |
| Turn-on time    | t <sub>ON</sub>  |   | 1           | ) / 2 | _   |      |
| Storage time    | t <sub>S</sub>   | $R_L = 1.9 \text{ k}\Omega$ (Note 5)<br>$V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$ | 7           | 25    | _   | μs   |
| Turn-off time   | tOFF             |   | $\bigcirc)$ | 50    | _   |      |

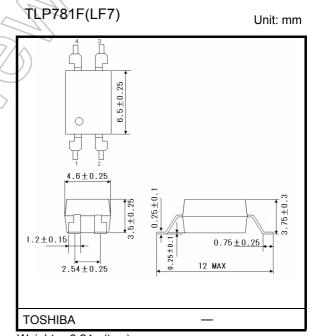




(Note 5): Switching time test circuit

## **Surface-Mount Lead Form Options**





Weight: 0.24g (typ.)

4

2014-09-08

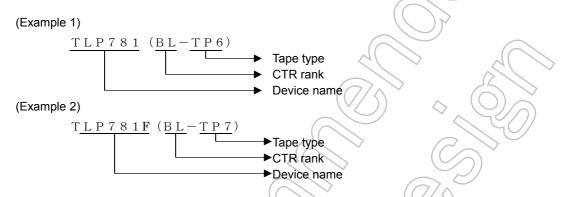
## Specifications for Embossed-Tape Packing: (TP6), (TP7)

### 1. Applicable Package

| Package Name | Product Type |
|--------------|--------------|
| DIP4LF6      | TLP781       |
| DIP4LF7      | TLP781F      |

#### 2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.



#### 3. Tape Dimensions

3.1 Orientation of Device in Relation to Direction of Tape Movement Device orientation in the recesses is as shown in Figure 1.

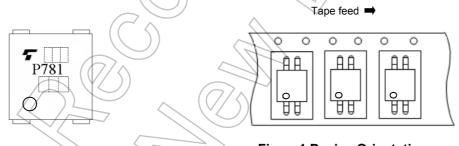


Figure1 Device Orientation

- 3.2 Tape Packing Quantity: 2000 devices per reel
- 3.3 Empty Device Recesses Are as Shown in Table 1.

**Table1 Empty Device Recesses** 

| -  |   |                           |  |
|----|---|---------------------------|--|
| // |   | Standard                  | Remarks  |
|    | Occurrences of 2 or more successive empty device recesses | 0                         | Within any given 40-mm section of tape, not including leader and trailer |
|    | Single empty device recesses                              | 6 devices (max.) per reel | Not including leader and trailer   |

#### 3.4 Start and End of Tape

The start of the tape has 30 or more empty holes. The end of the tape has 50 or more empty holes.

### 3.5 Tape Specification

#### [1] TLP781 (TP6)

- (1)Tape material: Plastic
- (2)Dimensions: The tape dimensions are as shown in Figure 2.

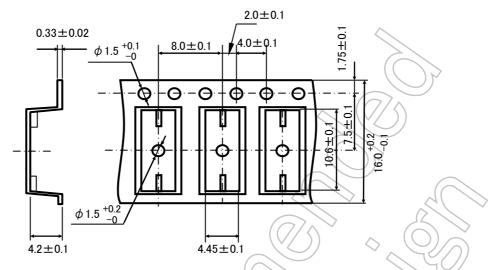


Figure 2 Tape Forms

#### [2] TLP781F (TP7)

- (1)Tape material: Plastic
- (2) Dimensions: The tape dimensions are as shown in Figure 3.

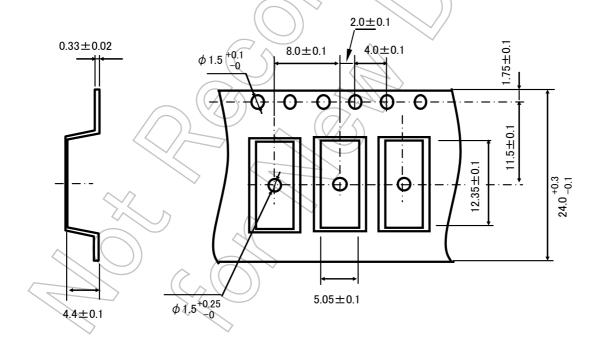


Figure 3 Tape Forms

#### 3.6 Reel Specification

#### [1] TLP781 (TP6)

(1)Material: Plastic

(2) Dimensions: The reel dimensions are as shown in Figure 4.

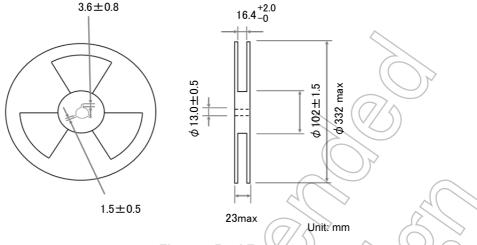


Figure 4 Reel Forms

#### [2] TLP781F (TP7)

(1)Material: Plastic

(2) Dimensions: The reel dimensions are as shown in Figure 5.

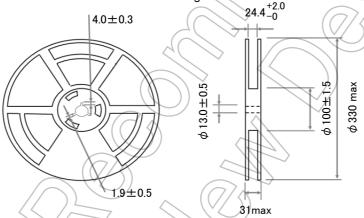


Figure 5 Reel Forms

#### 4. Packing

One reel of photocouplers is packed in a shipping carton.

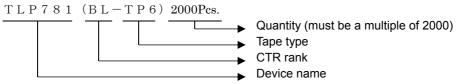
#### 5. Label Indication

The carton bears a label indicating the product number, the symbol representing classification of standard, the quantity, the lot number and the Toshiba company name.

#### 6. Ordering Information

When placing an order, please specify the product number, the CTR rank, the tape type and the quantity as shown in the following example.

#### (Example)



(Note): The order code may be suffixed with wither a letter or a digit.

Please contact your nearest Toshiba sales representative for more details.

## **Soldering and Storage**

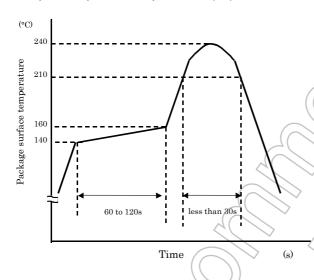
#### 1. Soldering

#### 1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

#### 1) Using solder reflow

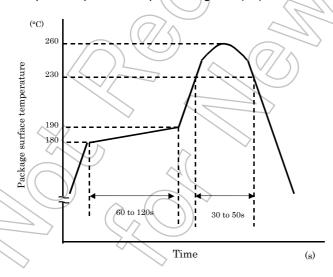
·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

- 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)
  - · Please preheat it at 150°C between 60 and 120 seconds.
  - · Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.
- 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

#### 2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



9 2014-09-08

#### **EN60747 Isolation Characteristics**

Types: TLP781, TLP781F

Type designations for 'option: (D4) ', which are tested under EN60747 requirements.

Ex.: TLP781 (D4-GR-LF6)

D4: EN60747 option
GR: CTR rank name

LF6: standard lead bend name

Note: Use TOSHIBA standard type number for safety standard application.

Ex. TLP781 (D4-GR-LF6) → TLP781

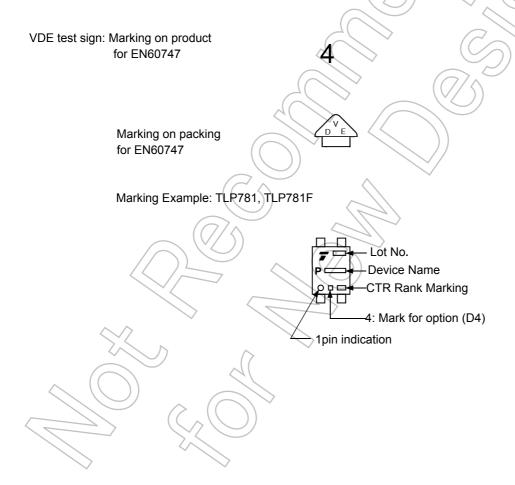
| Description   | Symbol  | Rating            | Unit           |
|---|---|-------------------|----------------|
| Application classification  |   |                   |                |
| for rated mains voltage ≤ 300 V <sub>rms</sub><br>for rated mains voltage ≤ 600 V <sub>rms</sub>  |   | I-III             | _              |
| Climatic classification   | 77/   | 55 / 115 / 21     | _              |
| Pollution degree  | (O) \( \daggered \).                                  | 2                 | _              |
| Maximum operating insulation voltage  | Viorm   | 890               | Vpk            |
| Input to output test voltage,<br>$Vpr = 1.5 \times V_{IORM}$ , type and sample test<br>$t_p = 10s$ , partial discharge < 5pC  | Vpr   | 1335              | Vpk            |
| Input to output test voltage, Vpr = 1.875×V <sub>IORM</sub> , 100% production test t <sub>p</sub> = 1s, partial discharge < 5pC                                       | V <sub>pr</sub>                                       | 1670              | Vpk            |
| Highest permissible overvoltage (transient overvoltage, t <sub>pr</sub> = 60s)  | V <sub>TR</sub>                                       | 6000              | Vpk            |
| Safety limiting values (max. permissible ratings in case of fault) current (input current $I_F$ , $P_{si}$ = 0) power (output or total power dissipation) temperature | I <sub>si</sub><br>P <sub>si</sub><br>T <sub>si</sub> | 300<br>500<br>150 | mA<br>mW<br>°C |
| Insulation resistance, V <sub>IO</sub> = 500V, Ta=25°C  | Rsi   | ≥10 <sup>12</sup> | Ω              |

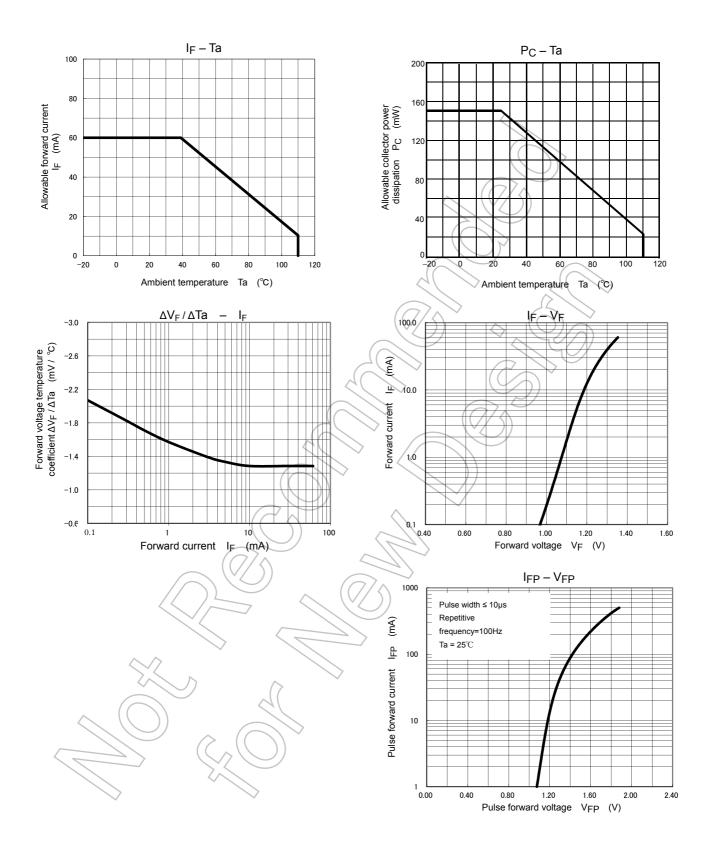
### **Insulation Related Specifications**

|                              |     | 7.62mm pitch<br>TLPxxx type | 10.16mm pitch<br>TLPxxxF type |
|------------------------------|-----|-----------------------------|-------------------------------|
| Minimum creepage distance    | Cr  | 6.5mm                       | 8.0mm                         |
| Minimum clearance            | CI  | 6.5mm                       | 8.0mm                         |
| Minimum insulation thickness | ti  | 0.4                         | m/m                           |
| Comparative tracking index   | CTI | 17                          | 75                            |

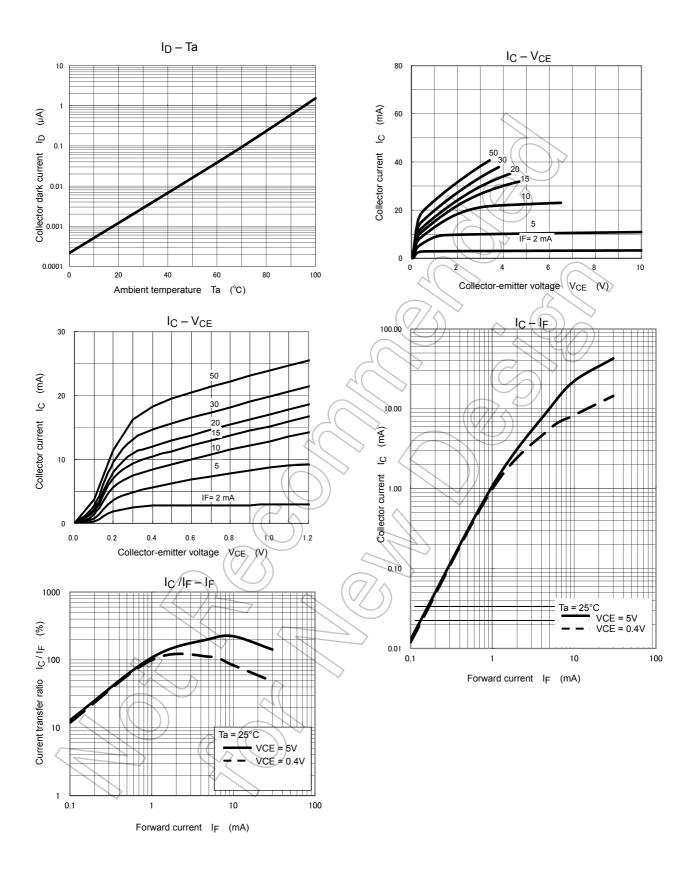
- (1) If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g. at a standard distance between soldering eye centres of 7.5mm). If this is not permissible, the user shall take suitable measures.
- (2) This photocoupler is suitable for 'safe electrical isolation' only within the safety limit data.

  Maintenance of the safety data shall be ensured by means of protective circuits.

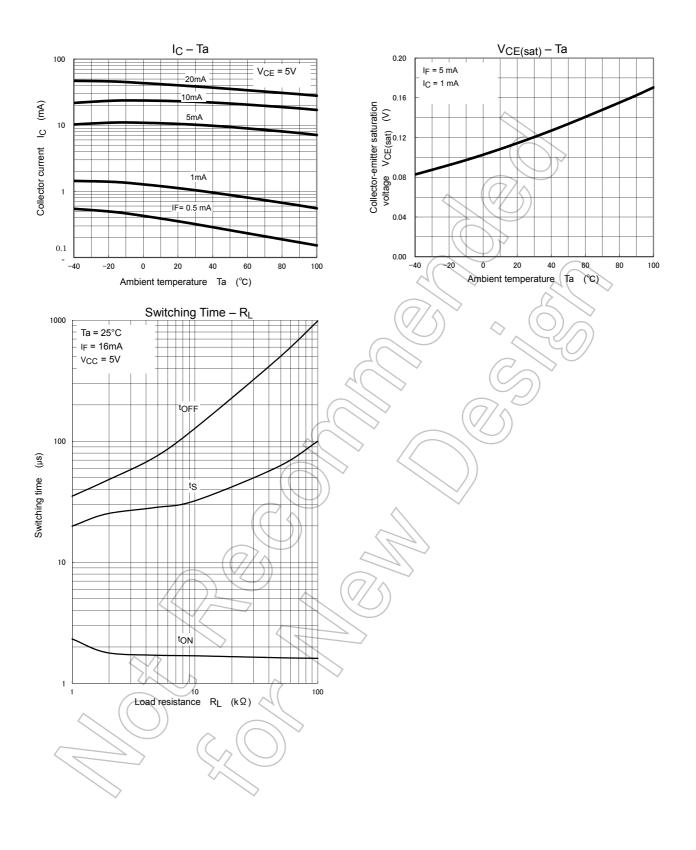




<sup>\*:</sup> The above graphs show typical characteristics.



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